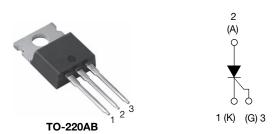


VS-25TTS...PbF Series, VS-25TTS...-M3 Series

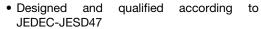
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Thyristor High Voltage, Phase Control SCR, 25 A



PRODUCT SUMMARY				
Package	TO-220AB			
Diode variation	Single SCR			
I _{T(AV)}	16 A			
V _{DRM} /V _{RRM}	800 V, 1200 V			
V _{TM}	1.25 V			
I _{GT}	45 mA			
TJ	- 40 °C to 125 °C			

FEATURES













APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding, and battery charge.

DESCRIPTION

The VS-25TTS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS					
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	18	22	А		

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I _{T(AV)}	Sinusoidal waveform	16	٨			
I _{RMS}		25	A			
V _{RRM} /V _{DRM}		800/1200	V			
I _{TSM}		320	A			
V_{T}	16 A, T _J = 25 °C	1.25	V			
dV/dt		500	V/µs			
dI/dt		150	A/μs			
T _J		- 40 to 125	°C			

VOLTAGE RATINGS						
PART NUMBER VRRM, MAXIMUM PEAK REVERSE VOLTAGE V V DRM, MAXIMUM PEAK DIRECT VOLTAGE V MA AT 125 °C MA						
VS-25TTS08PbF, VS-25TTS08-M3	800	800	10			
VS-25TTS12PbF, VS-25TTS12-M3	1200	1200	10			



VS-25TTS...PbF Series, VS-25TTS...-M3 Series

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ABSOLUTE MAXIMUM RATINGS									
DADAMETED	SYMBOL	TEST 001	NDITIONS	VALUES		UNITS			
PARAMETER	SYMBOL TEST CONDITIONS		TYP.	MAX.					
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° conduc	tion half sine wave	1	6				
Maximum RMS on-state current	I _{RMS}			2	5	Α			
Maximum peak, one-cycle,	1	10 ms sine pulse, rated \	/ _{RRM} applied	27	70	^			
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volt	age reapplied	32	20				
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied 10 ms sine pulse, no voltage reapplied		36	65	A ² s			
Maximum i-t for fusing	I-I			515		7 A-S			
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no volta	ge reapplied	5152		A²√s			
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.25		٧			
On-state slope resistance	r _t	T _J = 125 °C		2.0	mΩ				
Threshold voltage	V _{T(TO)}	1.0		.0	V				
Maximum various and divest leakage accurant	1 /1	T _J = 25 °C		0.	.5				
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C	$V_R = Rated V_{RRM}/V_{DRM}$	1	0				
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		-	150	mA			
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C			Anode supply = 6 V, resistive load, T _J = 25 °C		20	00	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80 \text{ °C, } V_{DRM} = R_g - k = Open$ 500		00	V/µs				
Maximum rate of rise of turned-on current	dl/dt			150		A/µs			

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P _{GM}		8.0	W	
Maximum average gate power	P _{G(AV)}		2.0	VV	
Maximum peak positive gate current	+ I _{GM}		1.5	Α	
Maximum peak negative gate voltage	- V _{GM}		10	٧	
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	60	mA	
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	45		
		Anode supply = 6 V, resistive load, T _J = 125 °C	20		
		Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5		
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	M	
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V	
Maximum DC gate voltage not to trigger	$V_{\sf GD}$	T 105 °C V Detectively	0.25		
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA	

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9		
Typical reverse recovery time	t _{rr}	T _J = 125 °C	4	μs	
Typical turn-off time	t _q	1J = 125	110		



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T_J , T_{Stg}		- 40 to 125	°C	
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.1		
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque -	minimum			6 (5)	kgf · cm	
Mounting torque —	maximum			12 (10)	(lbf · in)	
Marking dayion			Coop atula TO 220AP	25T	ΓS08	
Marking device			Case style TO-220AB		ΓS12	

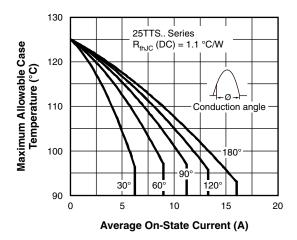


Fig. 1 - Current Rating Characteristics

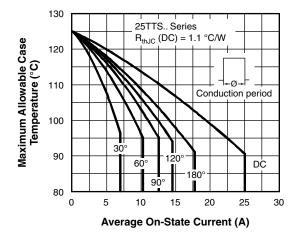


Fig. 2 - Current Rating Characteristics

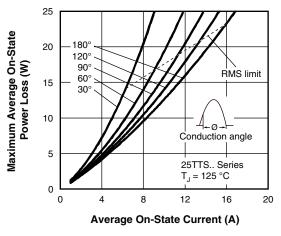


Fig. 3 - On-State Power Loss Characteristics

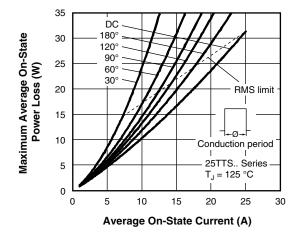


Fig. 4 - On-State Power Loss Characteristics

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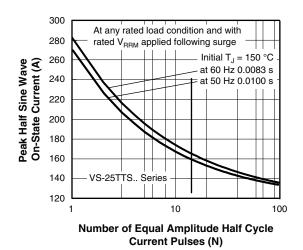


Fig. 5 - Maximum Non-Repetitive Surge Current

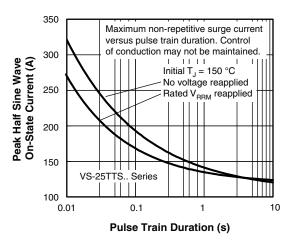


Fig. 6 - Maximum Non-Repetitive Surge Current

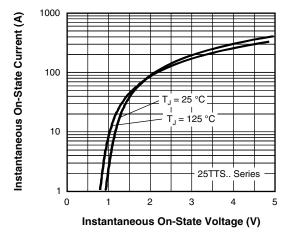


Fig. 7 - On-State Voltage Drop Characteristics

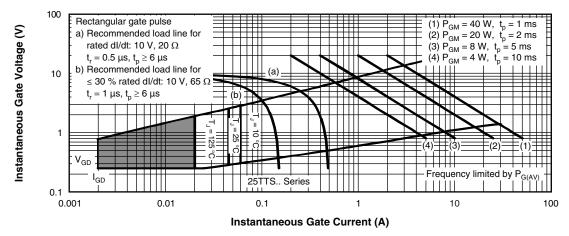


Fig. 8 - Gate Characteristics

VS-25TTS...PbF Series, VS-25TTS...-M3 Series

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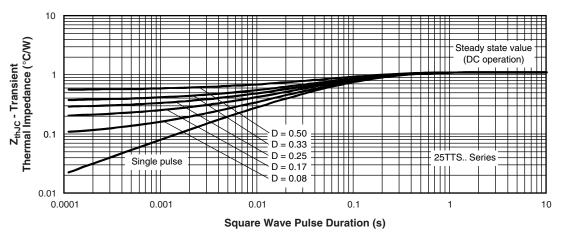
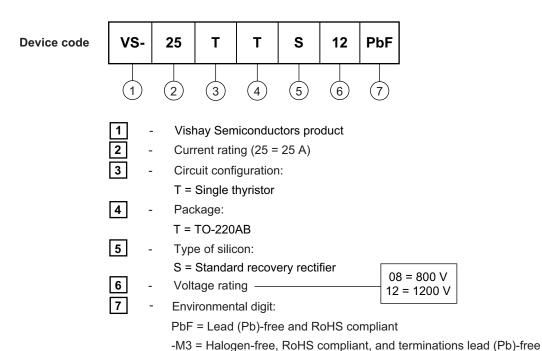


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-25TTS08PbF	50	1000	Antistatic plastic tubes			
VS-25TTS08-M3	50	1000	Antistatic plastic tubes			
VS-25TTS12PbF	50	1000	Antistatic plastic tubes			
VS-25TTS12-M3	50	1000	Antistatic plastic tubes			

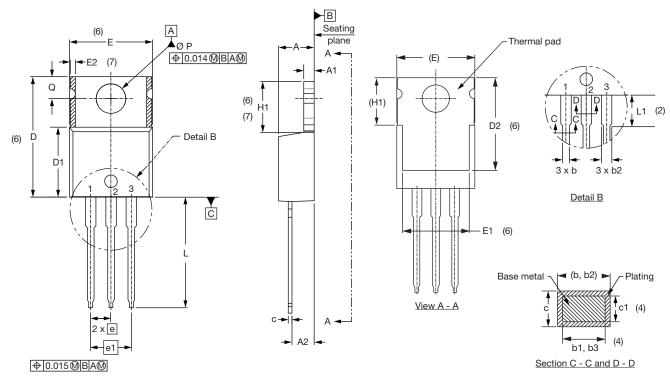
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95222</u>				
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -M3	www.vishay.com/doc?95028		



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Lead assignments

<u>Diodes</u>

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIMETERS INCHES		NOTES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000

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